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FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT					ATTY. DOCKET 033082 M 334		SERIAL NO. 10/585,828		
					APPLICANT:	CU7			
					Kenji SUZUKI, et al. FILING DATE GROUP ART UNIT				
					July 12, 2006		To Be Assigned		
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*Examiner's Initials		DOCUMENT NUMBER	DATE	NAME		CLASS	SUB- CLASS FILING DATE, IF APPROPRIATE		
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	AH	11-265992	9/28/1999		JAPAN			abstract	Γ.
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	AO	PCT Notification	on of Transmittal of Co	opies of	Translation of the	ne Internation	nal Prelir	minary	
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	AP	PCT Internation	nal Preliminary Repor	t on Pa	tentability (Form	PCT/IPEA/	109) date	d January	2004
	AQ	Chinese Office Action issued on April 4, 2008 with English language translation							
	AR	Korean Office	Action issued on May	29, 20	07				- 20
	AS	Korean non-patent document No. 2001-38SD-7-8, Roh et al., "Characteristics of Metal-oxide- Semiconductor (MOS) Devices withMetal", pages 513-519 (2001)							
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